

DIO57180

High Efficiency, 28 V, 1.5 A Synchronous Step-Down Regulator for Dimmable LED Driver

Features

- Wide input range: 4.75 V ~ 28 V
- Up to 1.5 A output current capability
- Low $R_{DS(ON)}$ for internal switches
High side/low side: 125 m Ω / 75 m Ω
- Fixed 1 MHz switching frequency
- Cycle-by-cycle 4.1 A peak current limit for high side
- High accuracy for low dimming scale
- Analog dimming with PWM input
- Over-temperature protection
- Compact package: TSOT23-6, DFN2*1.5-6

Descriptions

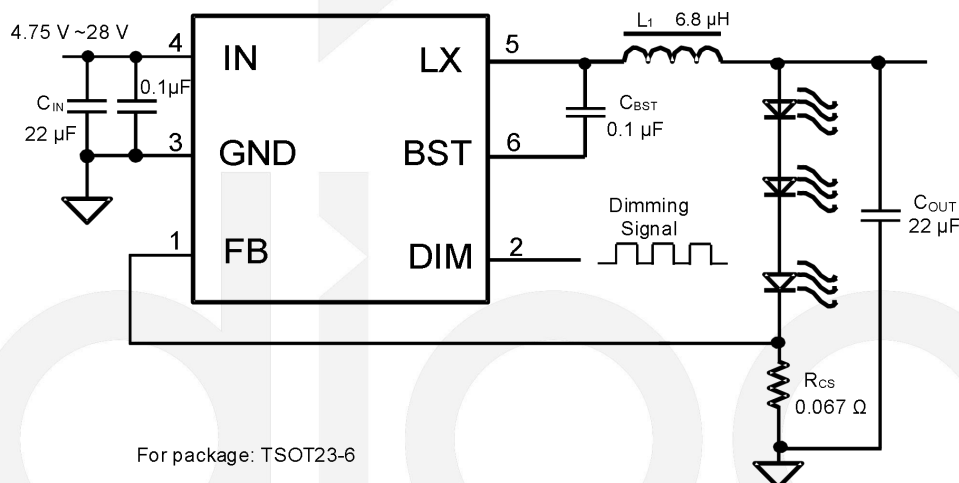
The DIO57180 is a high efficiency synchronous step-down LED regulator that achieves up to 1.5 A output current. It operates at 1 MHz and integrates two very low $R_{DS(ON)}$ power switches to minimize and reduce the external components.

It supports PWM dimming duty 0.5% ~ 100% to achieve dimmable LED lighting application.

Applications

- DVR or NVR (IP camera) system application
- 24 V DC lighting

Typical Applications



Ordering Information

| Ordering Part No. | Top Marking | RoHS | T _A | Package | |
|-------------------|-------------|-------|----------------|------------|-------------------|
| DIO57180TST6 | D8VW | Green | -40 to 85°C | TSOT23-6 | Tape & Reel, 3000 |
| DIO57180LT6 | 8VYW | Green | -40 to 85°C | DFN2*1.5-6 | Tape & Reel, 3000 |

Pin Assignment

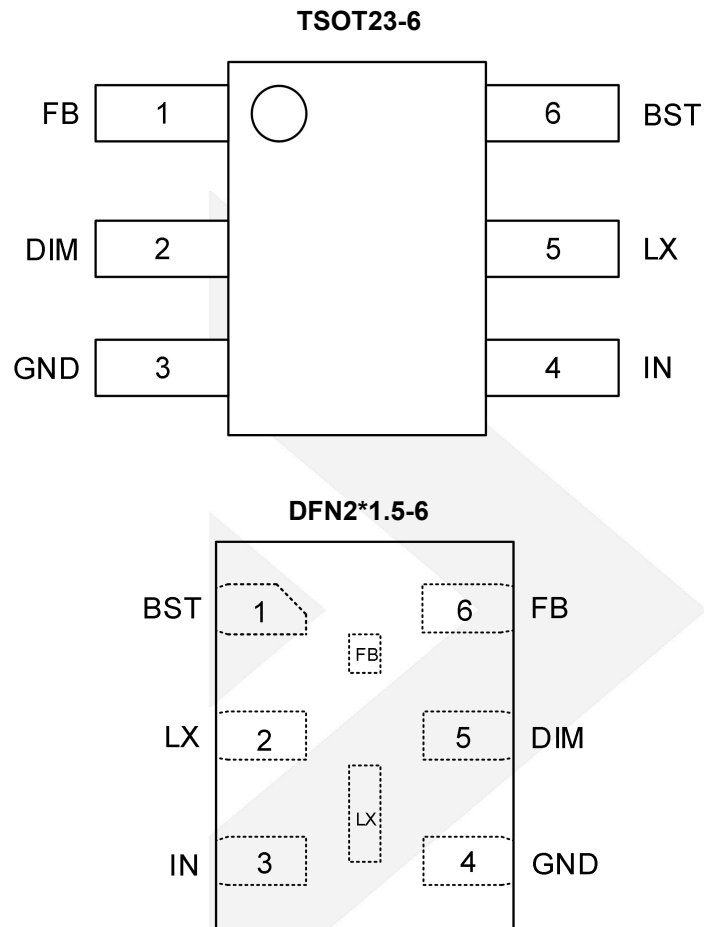


Figure 1. Pin assignment (Top view)

Pin Descriptions

| Name | Description |
|------|--|
| FB | Output current feedback pin. The output current: $I_{OUT} = 0.1 \text{ V} / R_{CS}$. |
| DIM | Dimming signal input. The PWM dimming duty range: 0.5% ~ 100%. Support the dimming frequency from 10 kHz to 100 kHz. |
| GND | Ground pin. |
| IN | Input supply pin. |
| LX | Switching node pin. Connect this pin to the inductor. |
| BST | Boot-strap pin. Supply for top side gate driver. Decouple this pin to LX with a 0.1 μF ceramic cap. |

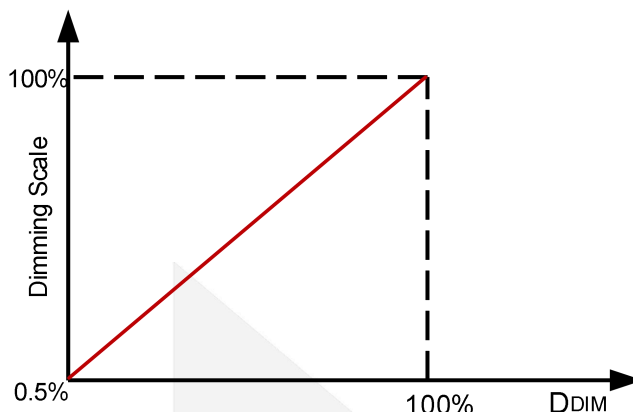


Figure 2. Ideal dimming curve of DIO57180 (dimming frequency 20 kHz)

Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. DIOO does not recommend exceeding them or designing to Absolute Maximum Ratings.

| Symbol | Parameter | | Rating | Unit |
|-------------------|--|---------------------|-------------|-----------------------------|
| $V_{IN, DIM, FB}$ | Voltage of IN, DIM, FB pins | | -0.3 to 38 | V |
| V_{LX} | Voltage of LX pin | | -0.3 to 38 | V |
| BST-LX | Voltage differential between BST and LX pins | | -0.3 to 5.5 | V |
| P_D | Power dissipation, $T_A = 25^\circ\text{C}$ | TSOT23-6 | 1.5 | W |
| | | DFN2*1.5-6 | 1.39 | |
| θ_{JA} | Package thermal resistance | Junction-to-ambient | 66 | $^\circ\text{C} / \text{W}$ |
| θ_{JC} | | Junction-to-case | 15 | $^\circ\text{C} / \text{W}$ |
| T_J | Junction temperature range | | -40 to 150 | $^\circ\text{C}$ |
| T_L | Lead temperature | | 260 | $^\circ\text{C}$ |
| T_{STG} | Storage temperature range | | -65 to 150 | $^\circ\text{C}$ |

Recommend Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended Operating conditions are specified to ensure optimal performance to the datasheet specifications.

| Symbol | Parameter | Rating | Unit |
|----------|----------------------------|------------|------------------|
| V_{IN} | Supply voltage IN | 4.75 to 28 | V |
| T_J | Junction temperature range | -40 to 125 | $^\circ\text{C}$ |

Electrical Characteristics

Typical value: $V_{IN} = 12\text{ V}$, $V_{OUT} = 3.6\text{ V}$, $I_{OUT} = 1.5\text{ A}$, $T_A = 25^\circ\text{C}$, unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------------------------|----------------------------------|--|------|------|-----|------------------|
| IN pin | | | | | | |
| V_{IN} | Input voltage range | | 4.75 | | 28 | V |
| V_{UVLO} | IN UVLO rising threshold | | | 4.0 | 4.2 | V |
| V_{UVLO_HYS} | UVLO hysteresis | | | 0.17 | | V |
| FB pin | | | | | | |
| V_{FB} | Feedback reference voltage | $D_{DIM} = 100\%$ | 97 | 100 | 103 | mV |
| Integrated power switches | | | | | | |
| $R_{DS(ON)1}^{(1)}$ | High side FET $R_{DS(ON)}$ | | | 125 | | mΩ |
| $R_{DS(ON)2}^{(1)}$ | Low side FET $R_{DS(ON)}$ | | | 75 | | mΩ |
| I_{LIM_HIGH} | High side FET peak current limit | | | 4.1 | | A |
| DIM pin | | | | | | |
| D_{DIM} | PWM dimming duty range | | 0.5 | | 100 | % |
| V_{DIM_ON} | Dimming ON threshold | | 1.5 | | | V |
| V_{DIM_OFF} | Dimming OFF threshold | | | | 0.4 | V |
| BST pin | | | | | | |
| V_{BST_LX} | Bias voltage for high FET driver | $4.75\text{ V} \leq V_{IN} \leq 28\text{ V}$ | | 5 | | V |
| f_s | Operating frequency | | | 1 | | MHz |
| t_{ON_MIN} | Min ON time | | | 100 | | ns |
| D_{MAX} | Max duty cycle | | | 95 | | % |
| Thermal shutdown | | | | | | |
| T_{SD} | Thermal shutdown temperature | | | 165 | | $^\circ\text{C}$ |
| T_{HYS} | Thermal shutdown hysteresis | | | 20 | | $^\circ\text{C}$ |

Note:

- (1) Guaranteed by design.
- (2) Specifications subject to change without notice.

Typical Performance Characteristics

Typical value: $V_{IN} = 12\text{ V}$, $I_{OUT} = 1.5\text{ A}$, 3 piece I_R LED, $T_A = 25^\circ\text{C}$, unless otherwise specified.

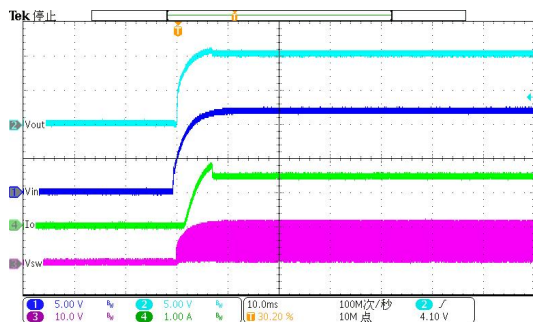


Figure 3. Start up

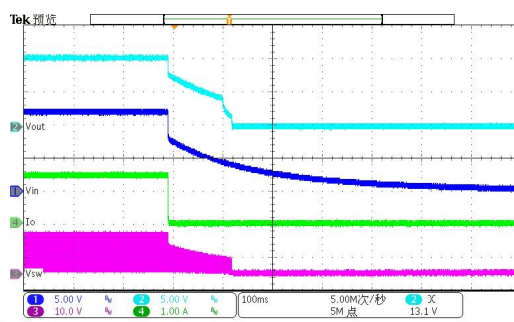


Figure 4. Shut down

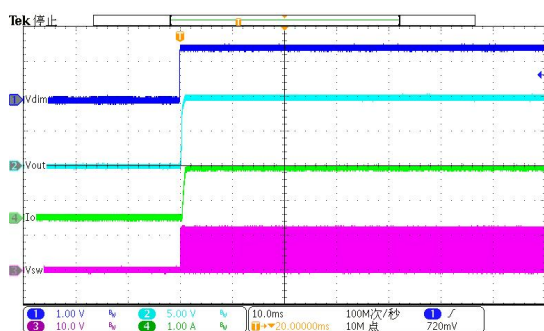


Figure 5. Dim on

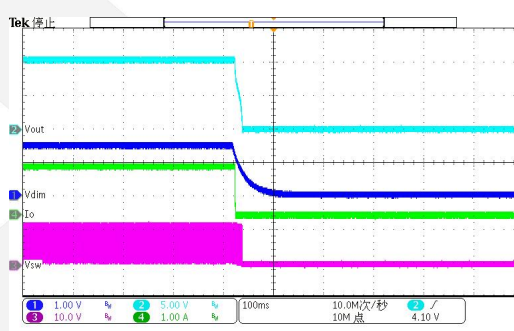
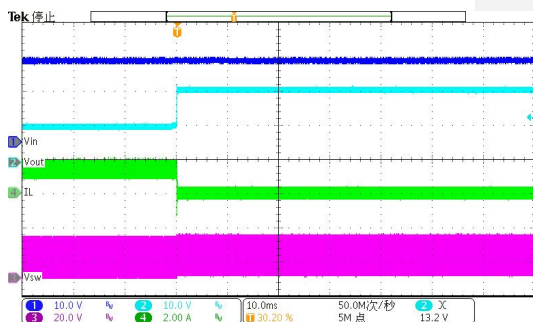
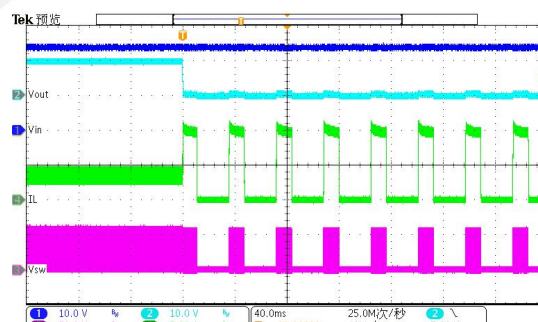


Figure 6. Dim off



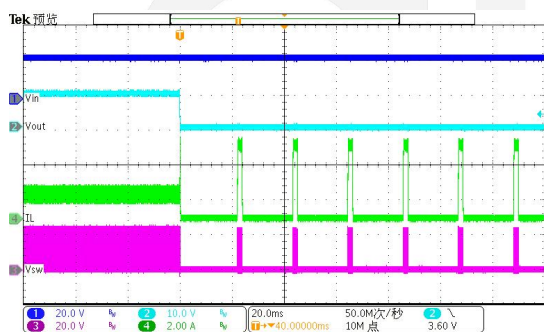
$V_{IN} = 24\text{ V}$, $V_{DIM} = 1.5\text{ V}$, $R_{CS} = 0.068\ \Omega$

Figure 7. Open LED test



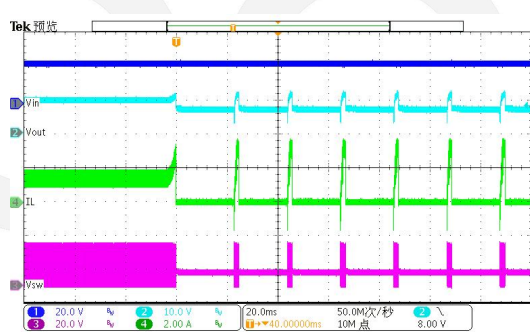
$V_{IN} = 24\text{ V}$, $V_{DIM} = 1.5\text{ V}$, $R_{CS} = 0.068\ \Omega$

Figure 8. Short LED test



$V_{IN} = 24\text{ V}$, $V_{DIM} = 1.5\text{ V}$, $R_{CS} = 0.068\ \Omega$

Figure 9. LED+ short to GND



$V_{IN} = 24\text{ V}$, $V_{DIM} = 1.5\text{ V}$, $R_{CS} = 0.068\ \Omega$

Figure 10. R_{CS} short

Functional Block Diagram

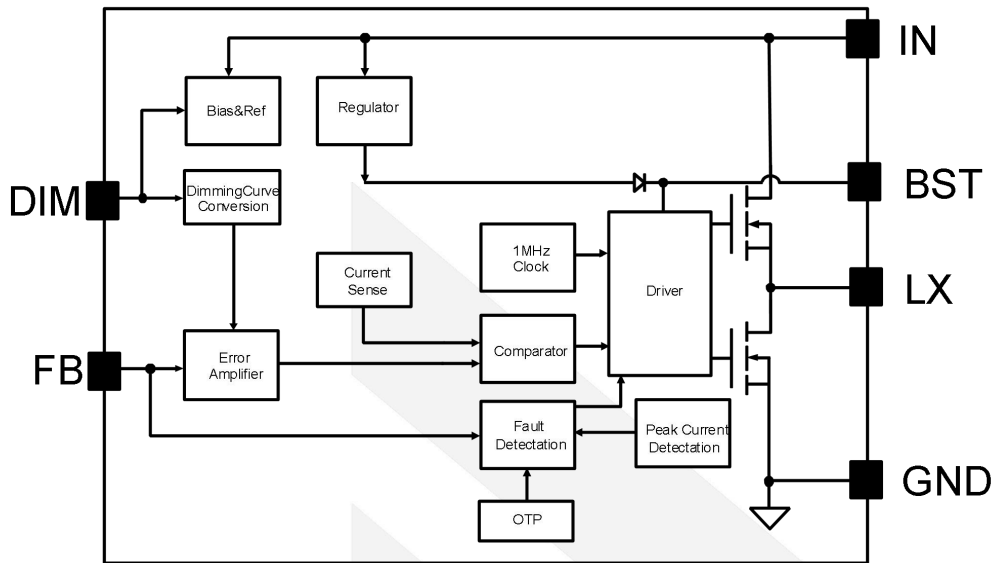


Figure 12. Functional block diagram

Operation

The DIO57180 is a synchronous buck regulator IC with a 28 V and up to 1.5 A constant output current capability. The device has two very low $R_{DS(ON)}$ power switches to minimize the switching transition loss and conduction loss. The high switching frequency minimizes the external inductor and capacitor size to reduce the cost and simplify the design. It supports the PWM dimming duty from 0.5% ~ 100% for DIM pin to achieve dimmable LED lighting application.

Application Information

Current sensing resistor R_{CS}

Choose the proper R_{CS} to program the output current I_{OUT} .

$$R_{CS} = \frac{0.1V}{I_{OUT}} \quad (1)$$

Input capacitor C_{IN}

The ripple current through input capacitor is calculated as the following equation.

$$I_{CIN_RMS} = I_{OUT} \times \sqrt{D \times (1 - D)} \quad (2)$$

A typical X7R or better grade ceramic capacitor with suitable capacitance should be chosen to handle this ripple current well. To minimize the potential noise problem, place this ceramic capacitor close to the IN and GND pins. Caution should be taken to minimize the loop area formed by C_{IN} and IN/GND pin.

Output capacitor C_{OUT}

The output capacitor is selected to improve the loop stability and handle the output current ripple noise requirements. For the best performance, use a X7R or better grade ceramic capacitor greater than 10 μF capacitance.

Main inductor L_1

There are several considerations in choosing this inductor.

- 1) Select the proper inductance to ensure the loop stability.
- 2) Choose the ripple current to be about 40% of the maximum output current as long as the loop stability allows. The inductance is calculated as the following equation.

$$L_1 = \frac{V_{OUT} \times (1 - \frac{V_{OUT}}{V_{IN, MAX}})}{f_s \times I_{OUT, MAX} \times 40\%} \quad (3)$$

Where f_s is the switching frequency and $I_{OUT, MAX}$ is the full scale LED current.

- 3) The saturation current rating of the inductor must be selected to be greater than the peak inductor current under full load conditions.

$$I_{SAT, MIN} > I_{OUT, MAX} + \frac{V_{OUT} \times (1 - \frac{V_{OUT}}{V_{IN, MAX}})}{2 \times f_s \times L_1} \quad (4)$$

Boost-strap capacitor C_{BST}

This capacitor provides the gate driver voltage for internal high side MOSFET. A low ESR more than 100 nF ceramic capacitor connected between BST pin and LX pin is recommended.

Dimming performance

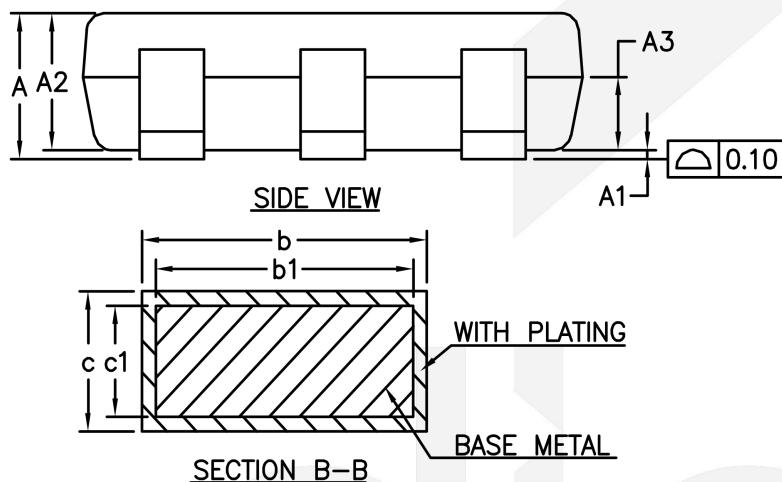
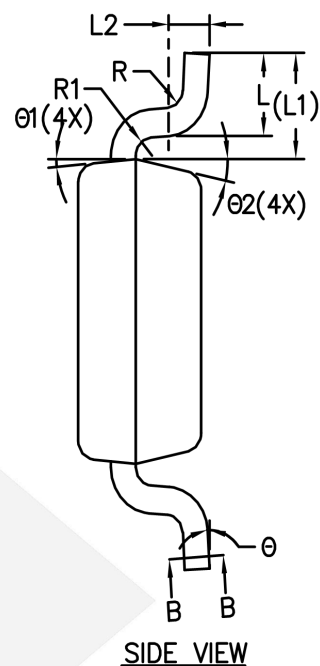
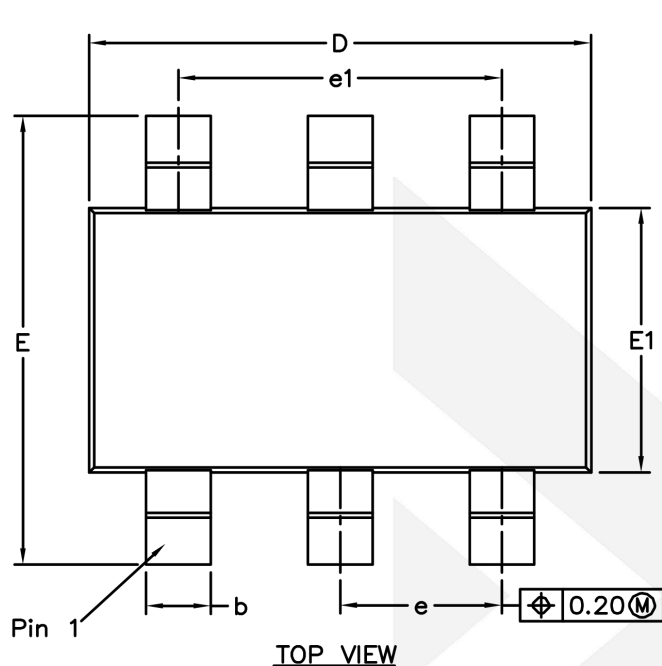
The DIM pin is used to regulate output current by the PWM signal, which supports the frequency from 10 kHz to 100 kHz. The logic high voltage is 1.5 V and the logic low voltage is 0.4 V. The DIM duty from 0.5% to 100%, the output current will be 0.5% ~ 100%, the ideal dimming curve as shown in figure 2.

Layout

For the best efficiency and minimum noise problems,

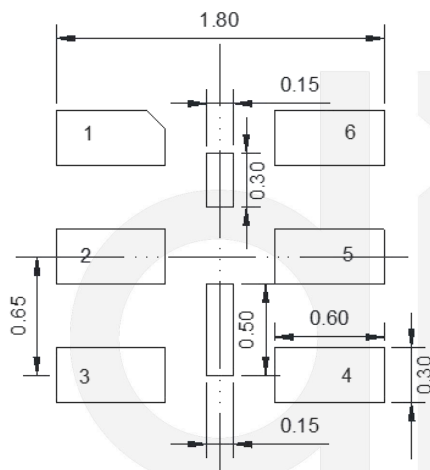
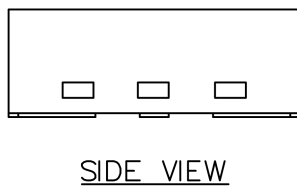
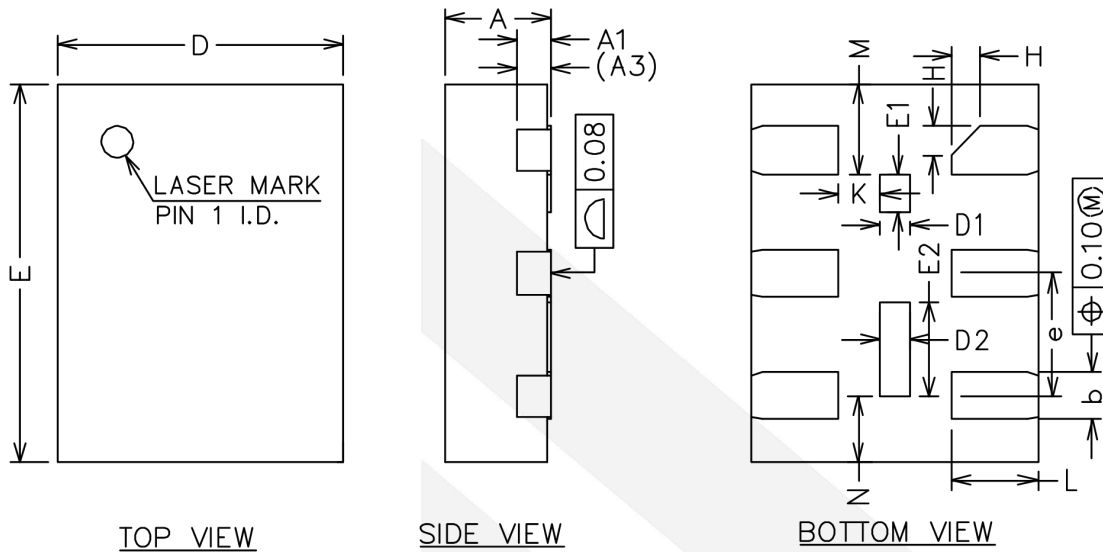
- 1) Maximize the PCB copper area connecting to GND pin to achieve the best thermal and noise performance. If the board space allowed, a ground plane is highly desirable.
- 2) C_{IN} must be close to the pins IN and GND. The loop area formed by C_{IN} and GND must be minimized.
- 3) The PCB copper area associated with LX pin must be minimized to avoid the potential noise problem.
- 4) The FB pin must not be adjacent to the LX line on the PCB layout to avoid the noised problem.

Physical Dimensions: TSOT23-6



| Common Dimensions (Units of measure = Millimeter) | | | |
|--|-----------|------|------|
| Symbol | Min | Nom | Max |
| A | - | - | 0.90 |
| A1 | 0 | - | 0.15 |
| A2 | 0.65 | 0.75 | 0.85 |
| A3 | 0.35 | 0.40 | 0.45 |
| b | 0.36 | - | 0.50 |
| b1 | 0.36 | 0.38 | 0.45 |
| c | 0.14 | - | 0.20 |
| c1 | 0.14 | 0.15 | 0.16 |
| D | 2.85 | 2.95 | 3.05 |
| E | 2.60 | 2.80 | 3.00 |
| E1 | 1.60 | 1.65 | 1.70 |
| e | 0.90 | 0.95 | 1.00 |
| e1 | 1.80 | 1.90 | 2.00 |
| L | 0.30 | 0.45 | 0.60 |
| L1 | 0.575 REF | | |
| L2 | 0.25 BSC | | |
| R | - | - | 0.25 |
| R1 | - | - | 0.25 |
| θ | 0° | - | 8° |
| θ1 | 3° | 5° | 7° |
| θ2 | 10° | 12° | 14° |

Physical Dimensions: DFN2*1.5-6



| Common Dimensions (Units of measure = Millimeter) | | | |
|--|-----------|------|------|
| Symbol | Min | Nom | Max |
| A | 0.50 | 0.55 | 0.60 |
| A1 | 0.00 | 0.02 | 0.05 |
| A3 | 0.152 REF | | |
| b | 0.20 | 0.25 | 0.30 |
| D | 1.40 | 1.50 | 1.60 |
| E | 1.90 | 2.00 | 2.10 |
| D1 | 0.05 | 0.15 | 0.25 |
| E1 | 0.10 | 0.20 | 0.30 |
| D2 | 0.05 | 0.15 | 0.25 |
| E2 | 0.40 | 0.50 | 0.60 |
| e | 0.55 | 0.65 | 0.75 |
| H | 0.15 REF | | |
| K | 0.10 | - | - |
| L | 0.35 | 0.45 | 0.55 |
| M | 0.33 | 0.48 | 0.63 |
| N | 0.20 | 0.35 | 0.50 |

CONTACT US

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